

SEMITOP® 3

IGBT Module

SK30GAD066T

Target Data

Features

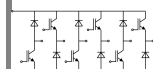
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Trench silicon structure
- High short circuit capability
- Low tail current with low temperature dependence
- Integrated PTC temperature sensor

Typical Applications*

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

Remarks

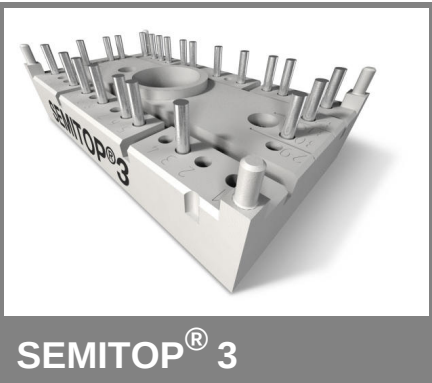
- PTC temp sensor test conditions:
measuring current: 1 mA
max measuring current value: 3 mA



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Absolute Maximum Ratings				$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions			Values	Units
IGBT					
V_{CES}	$T_j = 25\text{ °C}$			600	V
I_C	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$		38	A
		$T_s = 70\text{ °C}$		31	A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$			60	A
V_{GES}				± 20	V
t_{psc}	$V_{CC} = 360\text{ V}$; $V_{GE} \leq 20\text{ V}$; $T_j = 125\text{ °C}$ $V_{CES} < 600\text{ V}$			6	μs
Inverse Diode					
I_F	$T_j = 150\text{ °C}$	$T_s = 25\text{ °C}$			A
		$T_s = 80\text{ °C}$			A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$				A
Freewheeling Diode					
I_F	$T_j = 175\text{ °C}$	$T_{case} = 25\text{ °C}$		65	A
		$T_{case} = 70\text{ °C}$		51	A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$			200	A
Module					
$I_{t(RMS)}$					A
T_{vj}				-40 ... +175	$^{\circ}\text{C}$
T_{stg}				-40 ... +125	$^{\circ}\text{C}$
V_{isol}	AC, 1 min.			2500	V

Characteristics			T _s = 25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 0,43 mA		5	5,8	6,5	V
I _{CES}	V _{GE} = 0 V, V _{CE} = V _{CES} T _j = 25 °C T _j = 125 °C				0,08	mA mA
I _{GES}	V _{CE} = 0 V, V _{GE} = 30 V T _j = 25 °C T _j = 125 °C				300	nA nA
V _{CE0}	T _j = 25 °C T _j = 150 °C			0,9 0,85	1 0,9	V V
r _{CE}	V _{GE} = 15 V T _j = 25 °C T _j = 150 °C			18 27	28 38	mΩ mΩ
V _{CE(sat)}	I _{Cnom} = 30 A, V _{GE} = 15 V T _j = 25 °C _{chiplev.} T _j = 150 °C _{chiplev.}			1,45 1,65	1,85 2,05	V V
C _{ies} C _{oes} C _{res}	V _{CE} = 25, V _{GE} = 0 V f = 1 MHz					nF nF nF
t _{d(on)} t _r E _{on}	R _{Gon} = 22 Ω	V _{CC} = 300V I _C = 30A		1,24		ns ns mJ
t _{d(off)} t _f E _{off}	R _{Goff} = 22 Ω	T _j = 150 °C V _{GE} =±15V		1,48		ns ns mJ
R _{th(j-s)}	per IGBT			1,8		K/W



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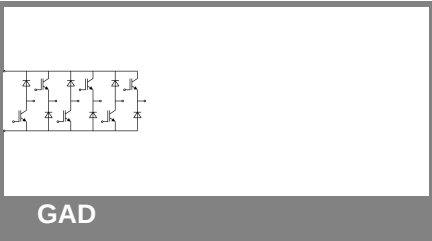
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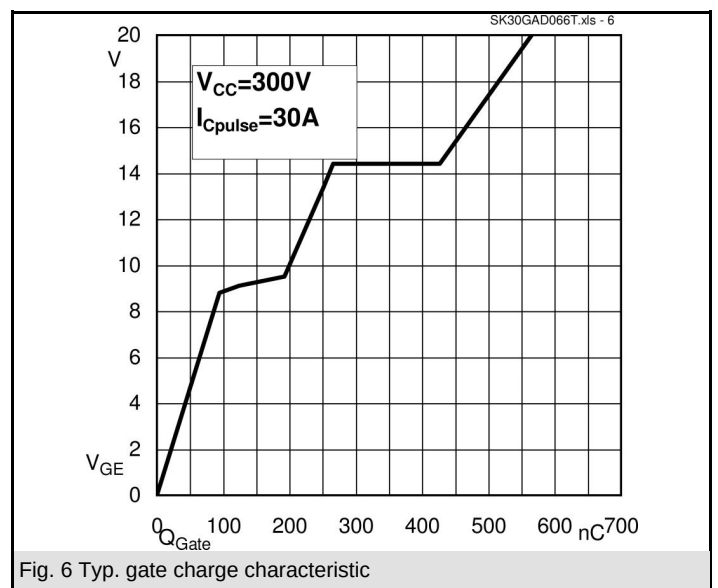
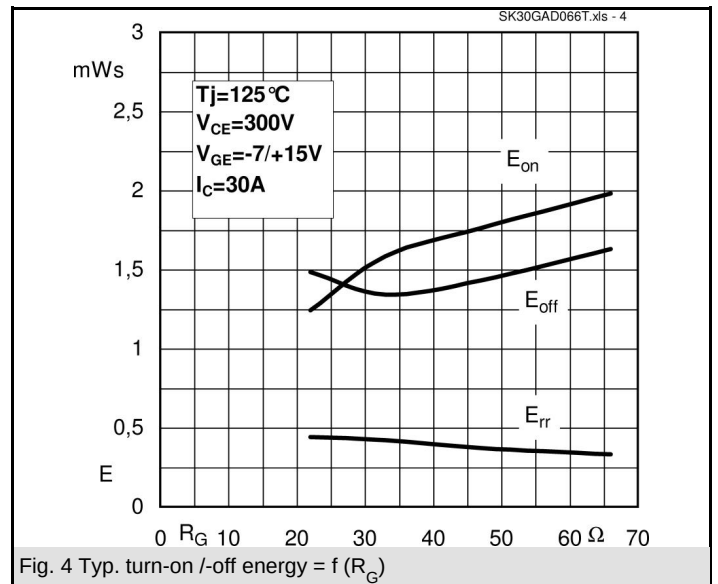
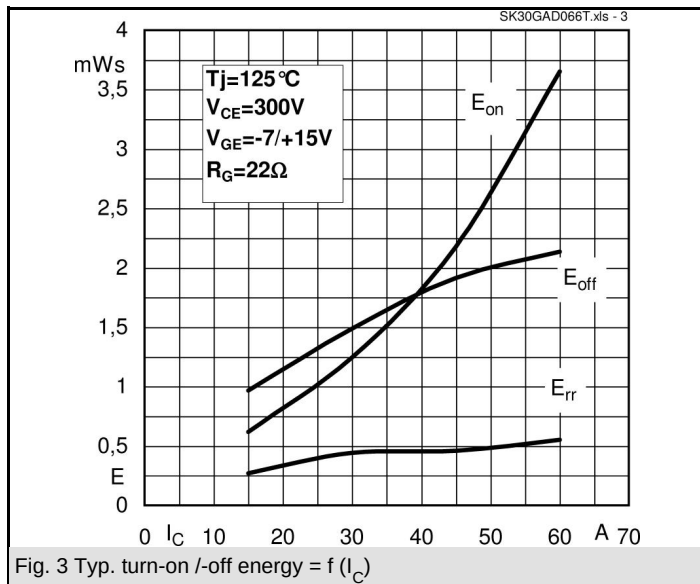
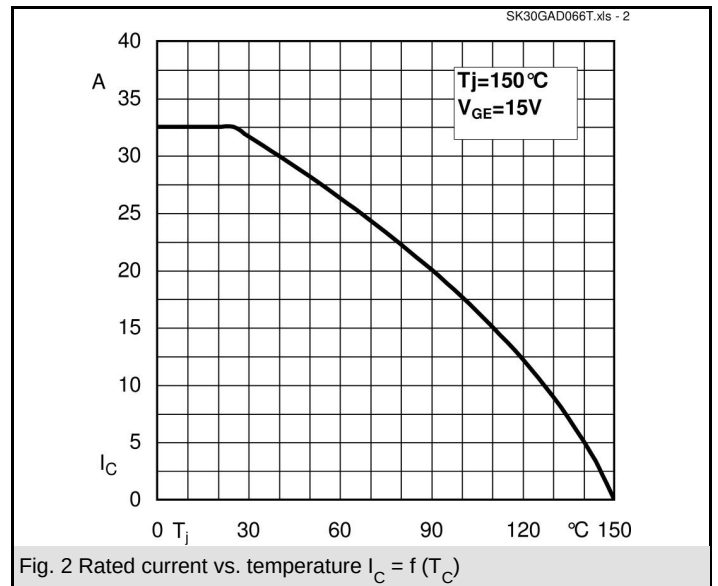
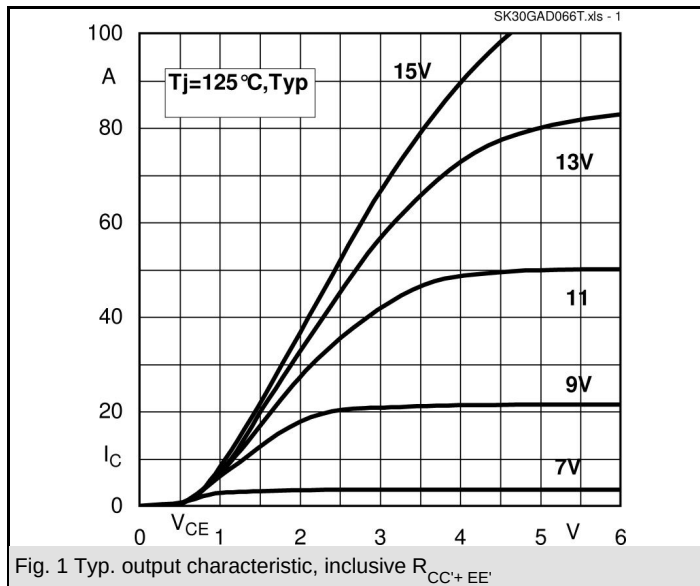
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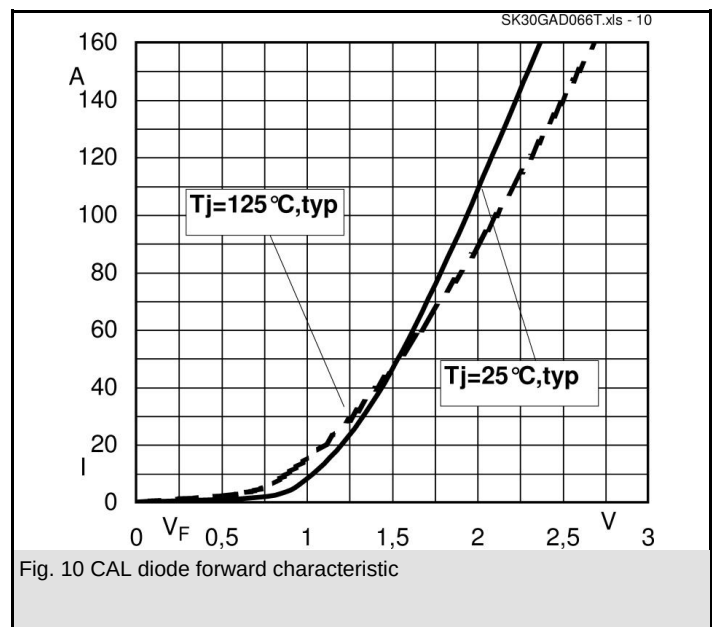
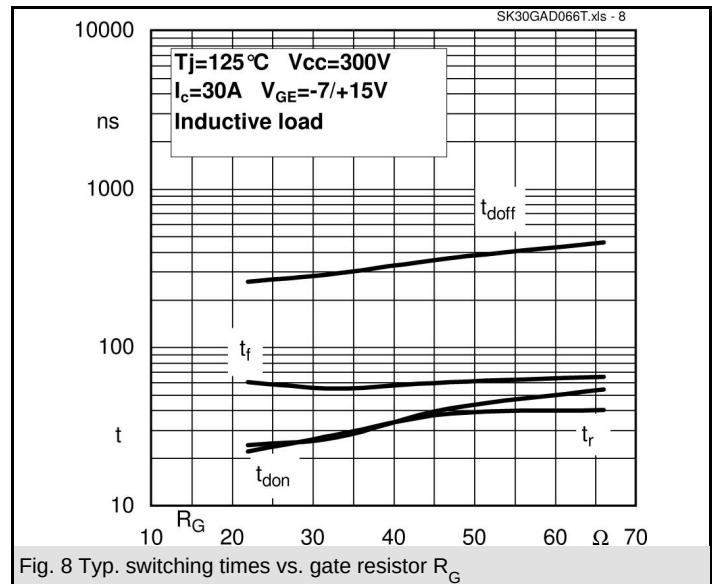
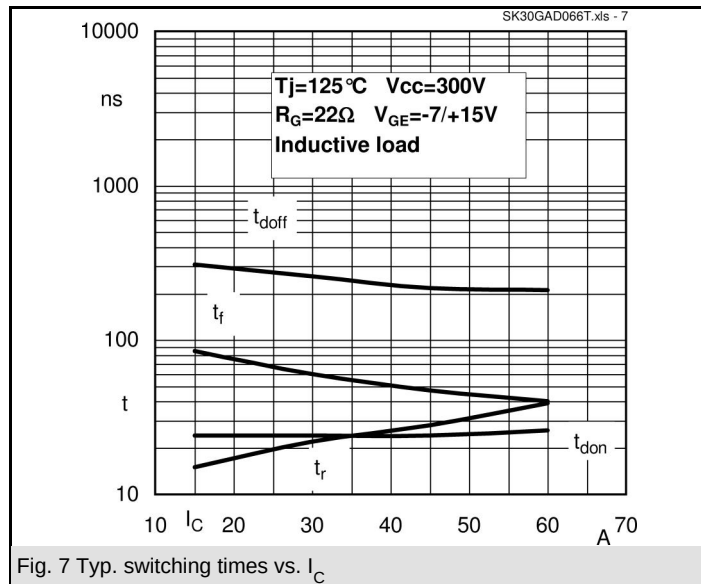


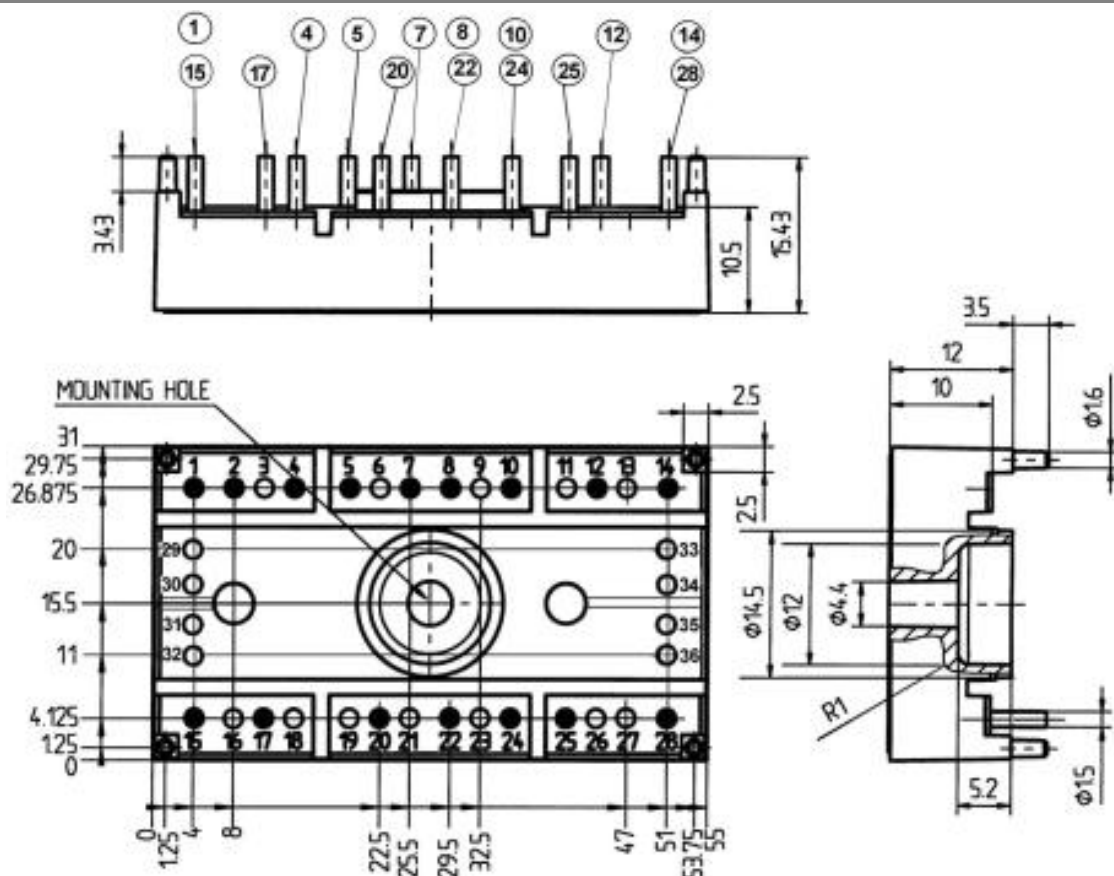
Characteristics					
Symbol	Conditions	min.	typ.	max.	Units
Freewheeling Diode					
$V_F = V_{EC}$	$I_{Fnom} = 30\text{ A}; V_{GE} = 0\text{ V}$		$T_j = 25\text{ }^{\circ}\text{C}_{chiplev.}$	1,3	1,5
			$T_j = 125\text{ }^{\circ}\text{C}_{chiplev.}$	1,2	1,45
V_{F0}	$T_j = 125\text{ }^{\circ}\text{C}$		0,85	0,9	V
r_F	$T_j = 125\text{ }^{\circ}\text{C}$		9	16	mΩ
I_{RRM}	$I_F = 30\text{ A}$		3		A
Q_{rr}	$di/dt = -500\text{ A/}\mu\text{s}$		3		μC
E_{rr}	$V_{CC} = 300\text{ V}$		0,44		mJ
$R_{th(j-s)FD}$	per diode			1,2	K/W
M_s	to heat sink M1	2,25		2,5	Nm
w			30		g
Temperature sensor					
R_{ts}	3%, $T_r = 25\text{ (100)}^{\circ}\text{C}$		1000 (1670)		Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

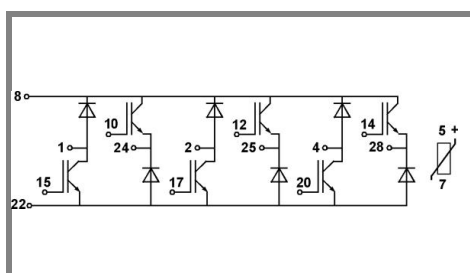
* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.







Case T57 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 57

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